MOTOROLA

MCM2532
MCM25L32

4096 × 8-BIT UV ERASABLE PROM

The MCM2532/25L32 is a 32,768-bit Erasable and Electrically Reprogrammable PROM designed for system debug usage and similar applications requiring nonvolatile memory that could be reprogrammed periodically. The transparent window in the package allows the memory content to be erased with ultraviolet light.

For ease of use, the device operates from a single power supply and has static power-down mode. Pin-for-pin compatible mask programmable ROMs are available for large volume production runs of systems initially using the MCM2532.

- Single +5 V Power Supply
- Organized as 4096 Bytes of 8 Bits
- Automatic Power-Down Mode (Standby)
- Fully Static Operation (No Clocks)
- TTL Compatible During Both Read and Program
- Maximum Access Time = 450 ns MCM2532
  350 ns MCM2532-35
  250 ns MCM2532-25
- Pin Compatible with MCM68A332 Mask Programmable ROMs
- Low Power Version
  MCM25L32 Active — 50 mA Max
          Standby — 10 mA Max
  MCM25L32-25 Active — 70 mA
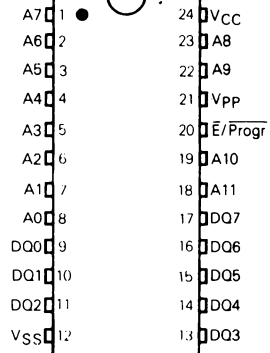   Standby — 15 mA

MOS
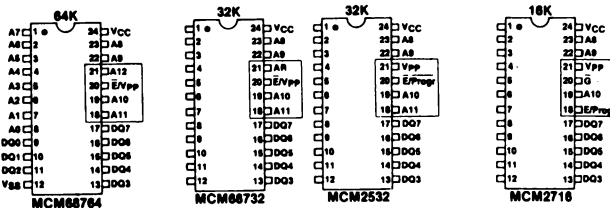### (N-CHANNEL, SILICON-GATE)

4096 × 8-BIT
UV ERASABLE PROM
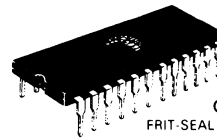
C SUFFIX
FRIT-SEAL CERAMIC PACKAGE
CASE 623A-02
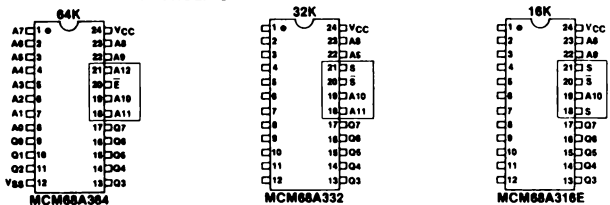
L SUFFIX CERAMIC PACKAGE
ALSO AVAILABLE — CASE 716

PIN ASSIGNMENT

A7	1	24	V_CC
A6	2	23	A8
A5	3	22	A9
A4	4	21	V_PP
A3	5	20	E̅/Progr
A2	6	19	A10
A1	7	18	A11
A0	8	17	DQ7
DQ0	9	16	DQ6
DQ1	10	15	DQ5
DQ2	11	14	DQ4
V_SS	12	13	DQ3

*PIN NAMES	
A	. . . . Address
DQ	. . . Data Input/Output
E̅/Progr	Dual Function Enable
	(Power-Down/Program Pulse)

*New Industry standard nomenclature

MOTOROLA'S PIN-COMPATIBLE EPROM FAMILY

MCM68764   MCM68732   MCM2532   MCM2716

MOTOROLA'S PIN-COMPATIBLE ROM FAMILY

MCM68A364   MCM68A332   MCM68A316E

INDUSTRY STANDARD PINOUTS

DS9816/4-80

2-96

MCM2532•MCM25L32

ABSOLUTE MAXIMUM RATINGS

Rating	Value	Unit
Temperature Under Bias	− 10 to + 80	°C
Operating Temperature Range	0 to + 70	°C
Storage Temperature	− 65 to + 125	°C
All Input/Output Voltages with Respect to V_{SS}	+ 6 to − 0.3	Vdc
V_{PP} Supply Voltage with Respect to V_{SS}	+ 28 to − 0.3	Vdc

NOTE: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to RECOMMENDED OPERATING CONDITIONS. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high-impedance circuit.

MODE SELECTION

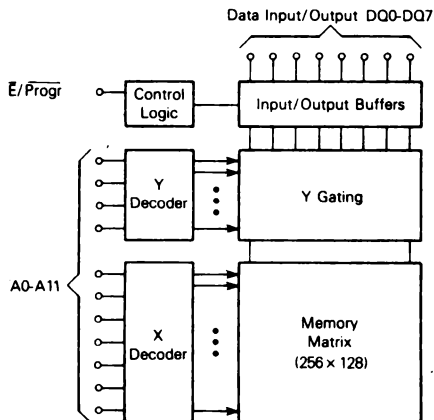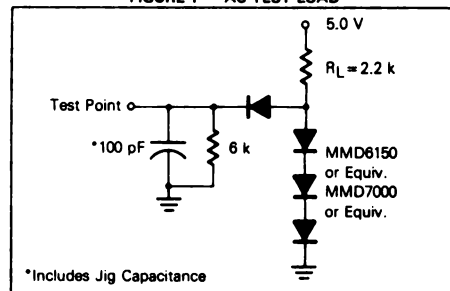| Mode	Pin Number				
	9-11, 13-17 DQ	12 V_{SS}	20 $\overline{E/Progr}$	21 V_{PP}	24 V_{CC}
Read	Data Out	V_{SS}	V_{IL}	5 V	V_{CC}
Output Disable	High Z	V_{SS}	V_{IH}	5 to 25 V	V_{CC}
Standby	High Z	V_{SS}	V_{IH}	5 V	V_{CC}
Program	Data In	V_{SS}	Pulsed V_{IH} to V_{IL}	V_{PPH}	V_{CC}
Program Verify	Data Out	V_{SS}	V_{IL}	5 V	V_{CC}
Program Inhibit	High Z	V_{SS}	V_{IH}	V_{PPH}	V_{CC}

BLOCK DIAGRAM

FIGURE 1 — AC TEST LOAD

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CAPACITANCE (f = 1.0 MHz, T_A = 25°C, periodically sampled rather than 100% tested.)

Characteristic	Symbol	Typ	Max	Unit
Input Capacitance (V_{in} = 0 V)	C_{in}	4.0	6.0	pF
Output Capacitance (V_{out} = 0 V)	C_{out}	8.0	12	pF

Capacitance measured with a Boonton Meter or effective capacitance calculated from the equation: $C = I\Delta_t/\Delta V$.

DC OPERATING CONDITIONS AND CHARACTERISTICS
(Fully operating voltage and temperature range unless otherwise noted)

RECOMMENDED DC OPERATING CONDITIONS

Parameter		Symbol	Min	Typ	Max	Unit
Supply Voltage*	MCM25L32/MCM2532	V_{CC}	4.75	5.0	5.25	Vdc
	MCM2532-35/MCM2532-25		4.5	5.0	5.5	
	MCM25L32-35/MCM25L32-25	V_{PP}	$V_{CC} - 0.6$	5.0	$V_{CC} + 0.6$	
Input High Voltage		V_{IH}	2.2	—	$V_{CC} + 1.0$	Vdc
Input Low Voltage		V_{IL}	−0.1	—	0.65	Vdc

RECOMMENDED DC OPERATING CHARACTERISTICS

Characteristic	Condition	Symbol	MCM2532 Min	MCM2532 Max	MCM25L32 Min	MCM25L32 Max	Unit
Address and $\overline{E}$ Input Sink Current	V_{in} = 5.25 V	I_{in}	—	10	—	10	μA
Output Leakage Current	V_{out} = 5.25 V	I_{LO}	—	10	—	10	μA
V_{CC} Supply Current* (Standby) — MCM2532 / MCM2532-35	$E = V_{IH}$	I_{CC1}	—	25	—	10	mA
V_{CC} Standby Current* (Standby) — MCM2532-25	$E = V_{IH}$	I_{CC1}	—	25	—	15	mA
V_{CC} Supply Current* (Active) — MCM2532 / MCM2532-35	$E = V_{IL}$	I_{CC2}	—	100	—	50	mA
V_{CC} Supply Current* (Active) — MCM2532-25	$E = V_{IL}$	I_{CC2}	—	120	—	70	mA
V_{PP} Supply Current*	V_{PP} = 5.85 V	I_{PP1}	—	5.0	—	5.0	mA
Output Low Voltage	I_{OL} = 2.1 mA	V_{OL}	—	0.45	—	0.45	V
Output High Voltage	I_{OH} = − 400 μA	V_{OH}	2.4	—	2.4	—	V

*V_{CC} must be applied simultaneously or prior to V_{PP}. V_{CC} must also be switched off simultaneously with or after V_{PP}. With V_{PP} connected directly to V_{CC} during the read operation, the supply current would be the sum of I_{PP1} and I_{CC}. The additional 0.6 V tolerance on V_{PP} makes it possible to use a driver circuit for switching V_{PP} supply from V_{CC} in Read mode to + 25 V for programming. Typical values are for T_A = 25°C and nominal supply voltages.

AC READ OPERATING CONDITIONS AND CHARACTERISTICS
(Full Operating Voltage and Temperature Range Unless Otherwise Noted)

Input Pulse Levels. . . . . 0.65 Volt and 2.2 Volts   Input and Output Timing Levels. . . . . 0.8 and 2.0 Volts
Input Rise and Fall Times. . . . . 20 ns   Output Load. . . . . See Figure 1

Characteristic	Symbol	MCM2532-25 Min	MCM2532-25 Max	MCM2532-35 Min	MCM2532-35 Max	MCM2532 Min	MCM2532 Max	Unit
Address Valid to Output Valid ($\overline{E}/\overline{Progr}$ = V_{IL})	t_{AVQV}	—	250	—	350	—	450	ns
$\overline{E}$ to Output Valid	t_{ELQV}	—	250	—	350	—	450	ns
$\overline{E}$ to High Z Output	t_{EHQZ}	0	100	0	100	0	100	ns
Data Hold from Address ($\overline{E}$ = V_{IL})	t_{AXDX}	0	—	0	—	0	—	ns

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READ MODE TIMING DIAGRAMS ($\overline{E} = V_{IL}$)
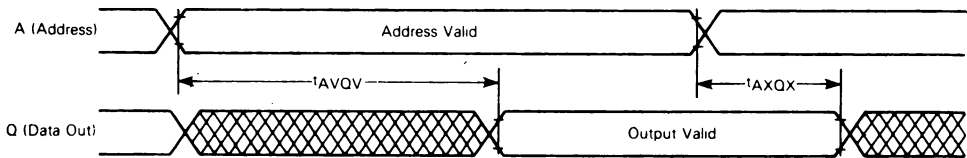
STANDBY MODE
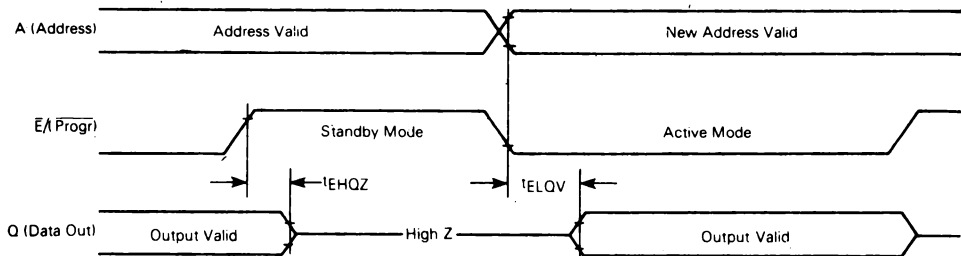
DC PROGRAMMING CONDITIONS AND CHARACTERISTICS
($T_A = 25°C \pm 5°C$)

RECOMMENDED PROGRAMMING OPERATION CONDITIONS

Parameter	Symbol	Min	Nom	Max	Unit
Supply Voltage	V_{CC}, V_{PPL}	4.75	5.0	5.25	Vdc
	V_{PPH}	24	25	26	
Input High Voltage for Data	V_{IH}	2.2	—	$V_{CC}+1$	Vdc
Input Low Voltage for Data	V_{IL}	−0.1	—	0.65	Vdc

*V_{CC} must be applied simultaneously or prior to V_{PP}. V_{CC} must also be switched off simultaneously with or after V_{PP}. The device must not be inserted into or removed from a board with V_{PP} at +25 V. V_{PP} must not exceed the +26 V maximum specifications.

PROGRAMMING OPERATION DC CHARACTERISTICS

Characteristic	Condition	Symbol	Min	Typ	Max	Unit
Address and $\overline{E}$/Progr Input Sink Current	$V_{in} = 5.25$ V/0.45 V	I_{LI}	—	—	10	µAdc
Vpp Supply Current (Vpp = 25 V ± 1 V)	$\overline{E}$/Progr = V_{IH}	I_{PP1}	—	—	10	mAdc
Vpp Programming Pulse Supply Current (Vpp = 25 V ± 1 V)	$\overline{E}$/Progr = V_{IL}	I_{PP2}	—	—	30	mAdc
V_{CC} Supply Current — MCM2532	—	I_{CC}	—	—	160	mAdc

AC PROGRAMMING OPERATING CONDITIONS AND CHARACTERISTICS

Characteristic	Symbol	Min	Max	Unit
Address Setup Time	t_{AVEL}	2.0	—	µs
Vpp Setup Time	t_{PHEL}	0	—	ns
Data Setup Time	t_{DVEL}	2.0	—	µs
Address Hold Time	t_{EHAX}	2.0	—	µs
Vpp to Enable Low Time	t_{PLEL}	0	—	ns
Data Hold Time	t_{EHQZ}	2.0	—	µs
Vpp Hold Time	t_{EHPL}	0	—	ns
Enable (Program) Active Time	t_{ELEH}	1*	55	ms
Enable (E/Progr) Pulse Transition Time	$t_{T(PE)}$	5	—	ns
Vpp Rise and Fall Time from 5 to 25 V	t_R, t_F	0.5	2	µs

*If shorter than 45 ms (min) pulses are used, the same number of pulses should be applied after the specific data has been verified.

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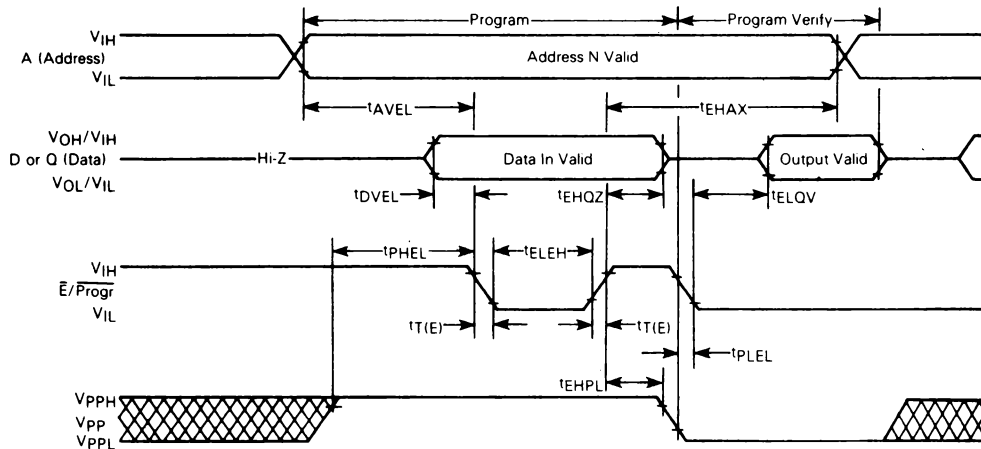
PROGRAMMING INSTRUCTIONS

After the completion of an ERASE operation, every bit in the device is in the "1" state (represented by Output High). Data are entered by programming zeros (Output Low) into the required bits. The words are addressed the same way as in the READ operation. A programmed "0" can only be changed to a "1" by ultraviolet light erasure.

To set the memory up for PROGRAM mode, the V_{PP} input (pin 21) should be raised to +25 V. The V_{CC} supply voltage is the same as for the READ operation. Programming data is entered in 8-bit words through the data out (DQ) terminals while $\overline{E}/\overline{Progr}$ is high. Only "0's" will be programmed when "0's" and "1's" are entered in the data word.

After address and data setup, a 50 ms program pulse (V_{IH} to V_{IL}) is applied to the $\overline{E}/\overline{Progr}$ input. A program pulse is applied to each address location to be programmed. To minimize programming time, a 2 ms pulse width is recommended. The maximum program pulse width is 55 ms; therefore, programming must not be attempted with a dc signal applied to the $\overline{E}/\overline{Progr}$ input.

Multiple MCM2532s may be programmed in parallel with the same data by connecting together like inputs and applying the program pulse to the $\overline{E}/\overline{Progr}$ inputs. Different data may be programmed into multiple MCM2532s connected in parallel by using the PROGRAM INHIBIT mode. Except for the $\overline{E}/\overline{Progr}$ pin, all like inputs may be common.

PROGRAM VERIFY for the MCM2532 is the read operation.
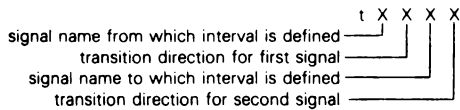
READ OPERATION

After access time, data is valid at the outputs in the READ mode.

ERASING INSTRUCTIONS

The MCM2532/25L32 can be erased by exposure to high intensity shortwave ultraviolet light, with a wave-length of 2537 angstroms. The recommended integrated dose (i.e., UV-intensity X exposure time) is 15 Ws/cm^2. As an example, using the "Model 30-000" UV-Eraser Turner Designs, Mountain View, CA94043) the ERASE-time is 36 minutes. The lamps should be used without shortwave filters and the MCM2532/25L32 should be positioned about one inch away from the UV-tubes.

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TIMING PARAMETER ABBREVIATIONS

```
                                          t  X  X  X  X
signal name from which interval is defined ──┘  │  │  │
transition direction for first signal ──────────┘  │  │
signal name to which interval is defined ───────────┘  │
transition direction for second signal ─────────────────┘
```

The transition definitions used in this data sheet are:
- H = transition to high
- L = transition to low
- V = transition to valid
- X = transition to invalid or don't care
- Z = transition to off (high impedance)

TIMING LIMITS

The table of timing values shows either a minimum or a maximum limit for each parameter. Input requirements are specified from the external system point of view. Thus, address setup time is shown as a minimum since the system must supply at least that much time (even though most devices do not require it). On the other hand, responses from the memory are specified from the device point of view. Thus, the access time is shown as a maximum since the device never provides data later than that time.

WAVEFORMS

Waveform Symbol	Input	Output
	Must Be Valid	Will Be Valid
	Change From H to L	Will Change From H to L
	Change From L to H	Will Change From L to H
	Don't Care Any Change Permitted	Changing State Unknown
		High Impedance